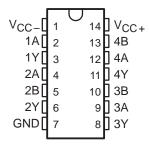
- Bi-MOS Technology With TTL and CMOS Compatibility
- Meets or Exceeds the Requirements of ANSI EIA/TIA-232-E and ITU Recommendation V.28
- Very Low Quiescent Current . . . 95 μA Typ V<sub>CC±</sub> = ±12 V
- Current-Limited Outputs . . . 10 mA Typ
- CMOS-and TTL-Compatible Inputs
- On-Chip Slew Rate Limited to 30 V/μs max
- Flexible Supply Voltage Range
- Characterized at V<sub>CC±</sub> of ±4.5 V and ±15 V
- Functionally Interchangeable With Texas Instruments SN75188, Motorola MC1488, and National Semiconductor DS14C88

#### D, DB<sup>†</sup>, OR N PACKAGE (TOP VIEW)



† The DB package is only available left-end taped and reeled, i.e., order device SN75C188DBLE.

### description

The SN75C188 is a monolithic, low-power, quadruple line driver that interfaces data terminal equipment with data communications equipment. This device is designed to conform to ANSI Standard EIA/TIA-232-E.

An external diode in series with each supply-voltage terminal is needed to protect the SN75C188 under certain fault conditions to comply with EIA/TIA-232-E.

The SN75C188 is characterized for operation from 0°C to 70°C.

#### **Function Tables**

DRIVER 1					
В	Υ				
Н	L				
L	Н				

DRIVERS 2 - 4

Α	В	Υ
Н	Н	L
L	X	Н
Х	L	Н

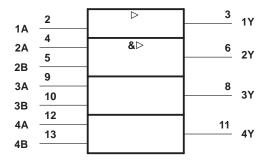
H = high level, L = low level, X = don't care



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

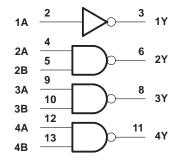


### logic symbol<sup>†</sup>



<sup>†</sup> This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

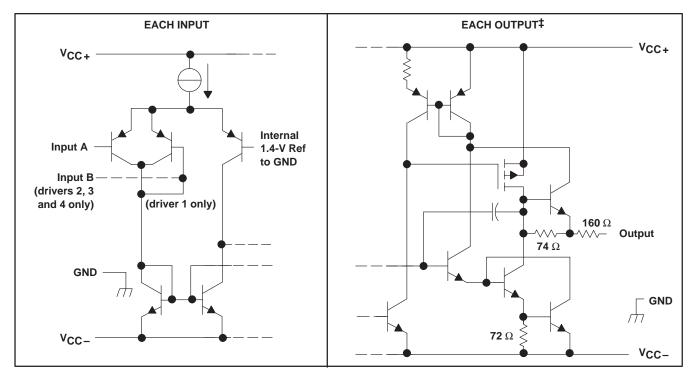
### logic diagram (positive logic)



positive logic

 $Y = \overline{A} (driver 1)$   $Y = \overline{AB} \text{ or } \overline{A} + \overline{B} (drivers 2 \text{ through 4})$ 

### schematics of inputs and outputs



<sup>‡</sup> All resistor values shown are nominal.



### absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage, V <sub>CC+</sub> (see Note 1)	15 V
Supply voltage, V <sub>CC</sub> (see Note 1)	
Input voltage range, V <sub>I</sub>	V <sub>CC</sub> to V <sub>CC+</sub>
Output voltage range, V <sub>O</sub>	$V_{CC-}$ -6 V to $V_{CC+}$ +6 V
Continuous total power dissipation	See Dissipation Rating Table
Operating free-air temperature range, T <sub>A</sub>	0°C to 70°C
Storage temperature range, T <sub>stq</sub>	–65°C to 150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: All voltage values are with respect to the network ground terminal.

#### **DISSIPATION RATING TABLE**

PACKAGE	T <sub>A</sub> ≤ 25°C POWER RATING	DERATING FACTOR ABOVE T <sub>A</sub> = 25°C	T <sub>A</sub> = 70°C POWER RATING		
D	950 mW	7.6 mW/°C	608 mW		
DB	525 mW	4.2 mW/°C	336 mW		
N	1150 mW	9.2 mW/°C	736 mW		

### recommended operating conditions

	MIN	NOM	MAX	UNIT
Supply voltage, V <sub>CC+</sub>	4.5	12	15	V
Supply voltage, V <sub>CC</sub> _	-4.5	-12	-15	V
Input voltage, V <sub>I</sub>	V <sub>CC</sub> -+2		VCC+	V
High-level Input voltage, VIH	2			V
Low-level Input voltage, V <sub>IL</sub>			0.8	V
Operating free-air temperature, T <sub>A</sub>	0		70	°C



# electrical characteristics over operating free-air temperature range, $V_{CC+}$ = 12 V, $V_{CC-}$ = -12 V (unless otherwise noted)

PARAMETER			MIN	TYP <sup>†</sup>	MAX	UNIT		
VOH	High-level output voltage	V <sub>II</sub> = 0.8 V,	$R_{I} = 3 k\Omega$	V <sub>CC+</sub> = 5 V, V <sub>CC-</sub> = -5 V	4			٧
VOH	riigii-ieveroutput voitage	V   L = 0.0 V,	N_ = 3 N22	V <sub>CC+</sub> = 12 V, V <sub>CC-</sub> = -12 V	10			V
Voi	Low-level output voltage	V <sub>IH</sub> = 2 V,	$R_1 = 3 k\Omega$	V <sub>CC+</sub> = 5 V, V <sub>CC-</sub> = -5 V			-4	٧
VOL (see Note 2)	(see Note 2)	VIH - 2 V,	N_ = 3 N22	V <sub>CC+</sub> = 12 V, V <sub>CC-</sub> = -12 V			-10	v
I <sub>IH</sub>	High-level input current	V <sub>I</sub> = 5 V					10	μΑ
IIL	Low-level input current	V <sub>I</sub> = 0					-10	μΑ
los(H)	High-level short-circuit output current‡	V <sub>I</sub> = 0.8 V,	VO = 0 or VCC-		-5.5	-10	-19.5	mA
IOS(L)	Low-level short-circuit output current‡	V <sub>I</sub> = 2 V,	$V_O = 0$ or $V_{CC} +$		5.5	10	19.5	mA
rO	Output resistance, power off	$V_{CC+} = 0$ ,	V <sub>CC</sub> -= 0,	$V_I = -2 V \text{ to } 2 V$	300			Ω
las	Supply current from V <sub>CC+</sub>	V <sub>CC+</sub> = 5 V, No load	V <sub>CC</sub> -=-5 V,	All inputs at 2 V or 0.8 V		90	160	μA
Icc+	Supply carrent norm vCC+	V <sub>CC+</sub> = 12 V, No load	V <sub>CC</sub> -=-12 V,	All inputs at 2 V or 0.8 V		95	160	μΑ
loo	Supply current from Voc	V <sub>CC+</sub> = 5 V, No load	V <sub>CC</sub> -=-5 V,	All inputs at 2 V or 0.8 V		-90	-160	
Icc-	Supply current from V <sub>CC</sub> _	V <sub>CC+</sub> = 12 V, No load	V <sub>CC</sub> -=-12	All inputs at 2 V or 0.8 V		-95	-160	μА

<sup>&</sup>lt;sup>†</sup> All typical values are at  $T_A = 25$ °C.

NOTE 2: The algebraic convention, in which the more positive (less negative) limit is designated as maximum, is used in this data sheet for logic levels only; e.g., if -4 V is a maximum, the typical value is a more negative voltage.

## switching characteristics, $V_{CC+}$ = 12 V, $V_{CC-}$ = -12 V, $T_A$ = 25°C

	PARAMETER	TEST CON	MIN	TYP	MAX	UNIT	
tPLH	Propagation delay time, low- to high-level output§	$R_L = 3 k\Omega$ ,	C <sub>L</sub> = 15 pF,			3	μs
t <sub>PHL</sub>	Propagation delay time, high- to low-level output§	See Figure 1				3.5	μs
tTLH	Transition time, low- to high-level output			0.53		3.2	μs
<sup>t</sup> THL	Transition time, high- to low-level output			0.53		3.2	μs
tTLH	Transition time, low- to high-level output#	$R_L = 3 k\Omega$ to $7 k\Omega$ ,	C <sub>L</sub> = 2500 pF,		1.5		μs
<sup>t</sup> THL	Transition time, high- to low-level output#	See Figure 1			1.5		μs
SR	Output slew rate§	$R_L = 3 k\Omega \text{ to } 7 k\Omega$	C <sub>L</sub> = 15 pF	6	15	30	V/μs

<sup>§</sup> Measured at the 50% level

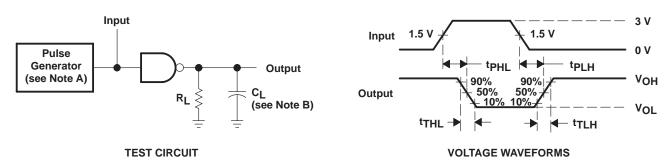


<sup>‡</sup> Not more than one output should be shorted at a time.

<sup>¶</sup> Measured between the 10% and 90% points on the output waveform

<sup>#</sup> Measured between the 3-V and -3-V points on the output waveform (EIA/TIA-232-E conditions), all unused inputs tied either high or low

### PARAMETER MEASUREMENT INFORMATION



NOTES: A. The pulse generator has the following characteristics:  $t_W$  = 25  $\mu$ s, PRR = 20 kHZ,  $Z_O$  = 50  $\Omega$ ,  $t_f$  =  $t_f$   $\leq$  50 ns.

B. C<sub>L</sub> includes probe and jig capacitance.

Figure 1. Test Circuit and Voltage Waveforms

### **TYPICAL CHARACTERISTICS**

#### **VOLTAGE TRANSFER CHARACTERISTICS** 15 $V_{CC\pm} = \pm 15 V$ V<sub>CC±</sub> = ±12 V 12 $V_{CC\pm} = \pm 9 V$ 9 V<sub>O</sub> - Output Voltage - V $V_{CC\pm} = \pm 5 V$ 6 3 0 $V_{CC\pm} = \pm 5 V$ -3-6 $V_{CC\pm} = \pm 9 V$ $V_{CC\pm} = \pm 12 V$ -9 $R_L = 3 k\Omega$ $V_{CC\pm}$ = $\pm 5$ V -12T<sub>A</sub> = 25°C 0.2 0.4 0.6 0.8 1 1.2 1.4 1.6 1.8 0 V<sub>I</sub> - Input Voltage - V

Figure 2

### SHORT-CIRCUIT OUTPUT CURRENT FREE-AIR TEMPERATURE 15 $V_{CC\pm} = \pm 12 V$ IOS - Short-Circuit Output Current - mA 10 I<sub>OS(L)</sub> V<sub>I</sub> = 2 V 5 $V_O = 0$ or $V_{CC+}$ 0 -5 $I_{OS(H)}$ $V_{I} = 0.8 V$ $V_O = 0$ or $V_{CC}$ -10-1520 60 80 100 120

Figure 4

T<sub>A</sub> - Free-Air Temperature - °C

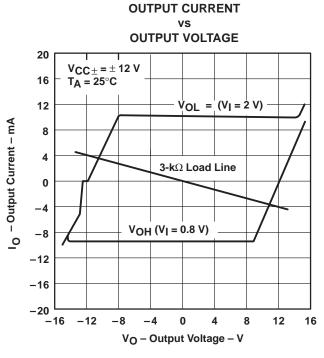
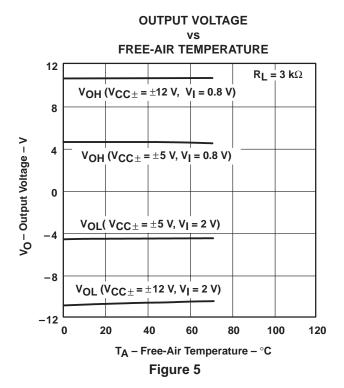


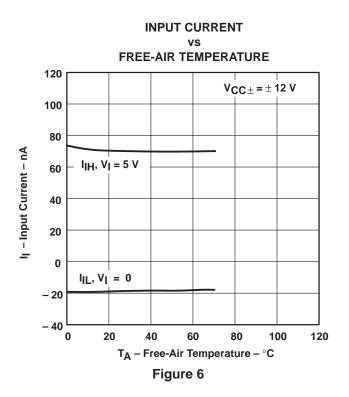
Figure 3

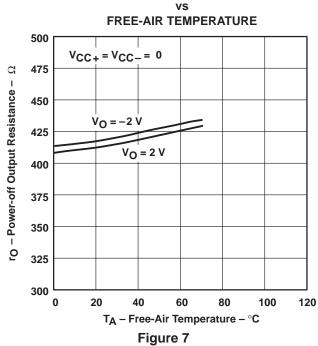


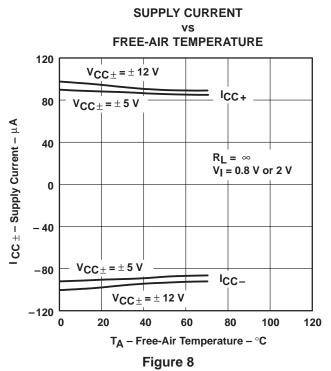


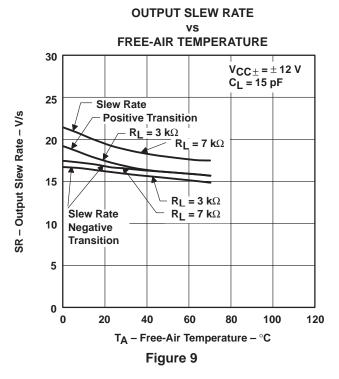
**POWER-OFF OUTPUT RESISTANCE** 

### **TYPICAL CHARACTERISTICS**

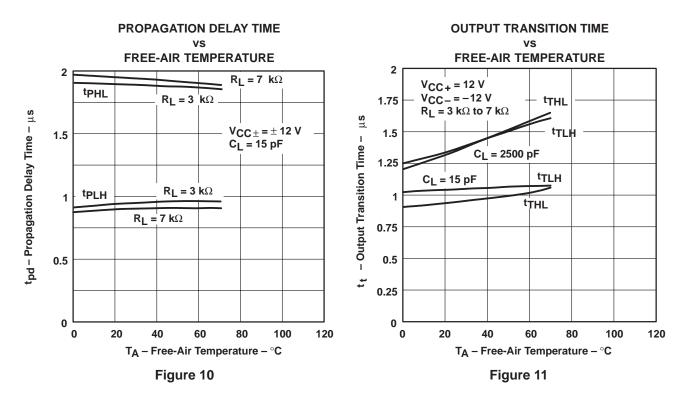








#### TYPICAL CHARACTERISTICS



### **APPLICATION INFORMATION**

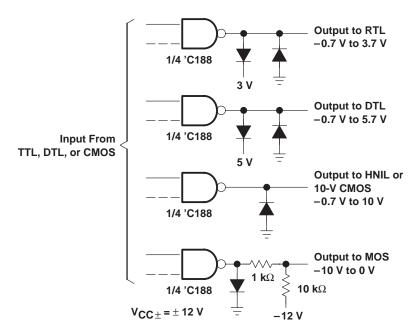
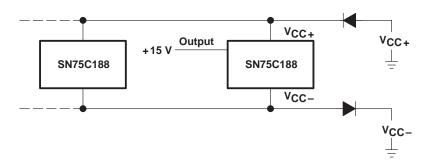


Figure 12. Logic Translator Applications



### **APPLICATION INFORMATION**



NOTE A: External diodes placed in series with the  $V_{CC-}$  and  $V_{CC-}$  leads protect the SN75C188 in the fault condition where the device outputs are shorted to  $\pm$ 15 V and the power supplies are at low voltage and provide low-impedance paths to GND.

Figure 13. Power Supply Protection to Meet Power-Off Fault Conditions of Standard EIA/TIA-232-E





.com 4-Jun-2007

### **PACKAGING INFORMATION**

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan <sup>(2)</sup>	Lead/Ball Finish	MSL Peak Temp <sup>(3)</sup>
SN75C188D	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75C188DBLE	OBSOLETE	SSOP	DB	14		TBD	Call TI	Call TI
SN75C188DBR	ACTIVE	SSOP	DB	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75C188DBRE4	ACTIVE	SSOP	DB	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75C188DBRG4	ACTIVE	SSOP	DB	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75C188DE4	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75C188DG4	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75C188DR	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75C188DRE4	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75C188DRG4	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75C188N	ACTIVE	PDIP	N	14	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
SN75C188NE4	ACTIVE	PDIP	N	14	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
SN75C188NSR	ACTIVE	SO	NS	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75C188NSRE4	ACTIVE	SO	NS	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75C188NSRG4	ACTIVE	SO	NS	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

<sup>(1)</sup> The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free** (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

**Green (RoHS & no Sb/Br):** TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.



### PACKAGE OPTION ADDENDUM

4-Jun-2007

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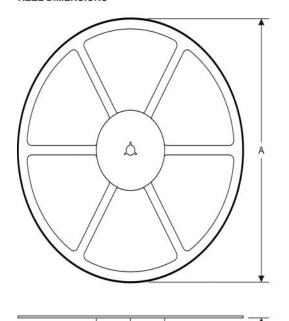
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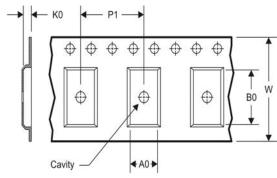
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### TAPE AND REEL INFORMATION

### REEL DIMENSIONS







A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

### TAPE AND REEL INFORMATION

\*All dimensions are nominal

Device		Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN75C188DBR	SSOP	DB	14	2000	330.0	16.4	8.2	6.6	2.5	12.0	16.0	Q1
SN75C188DR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
SN75C188DR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
SN75C188NSR	SO	NS	14	2000	330.0	16.4	8.2	10.5	2.5	12.0	16.0	Q1

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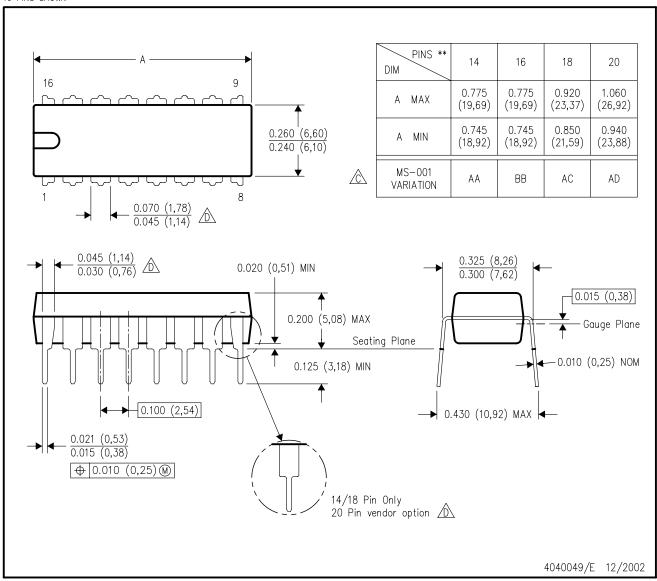
\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN75C188DBR	SSOP	DB	14	2000	367.0	367.0	38.0
SN75C188DR	SOIC	D	14	2500	333.2	345.9	28.6
SN75C188DR	SOIC	D	14	2500	367.0	367.0	38.0
SN75C188NSR	SO	NS	14	2000	367.0	367.0	38.0

### N (R-PDIP-T\*\*)

### PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN

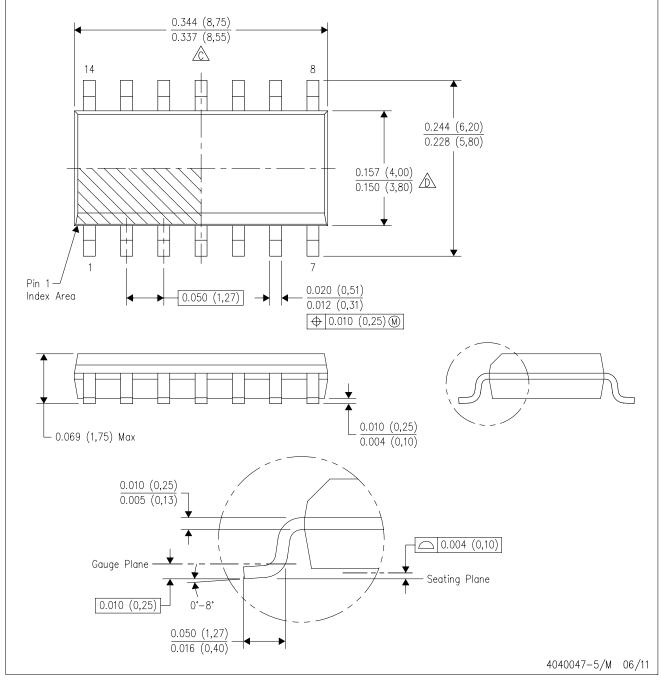


- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.



### D (R-PDSO-G14)

### PLASTIC SMALL OUTLINE

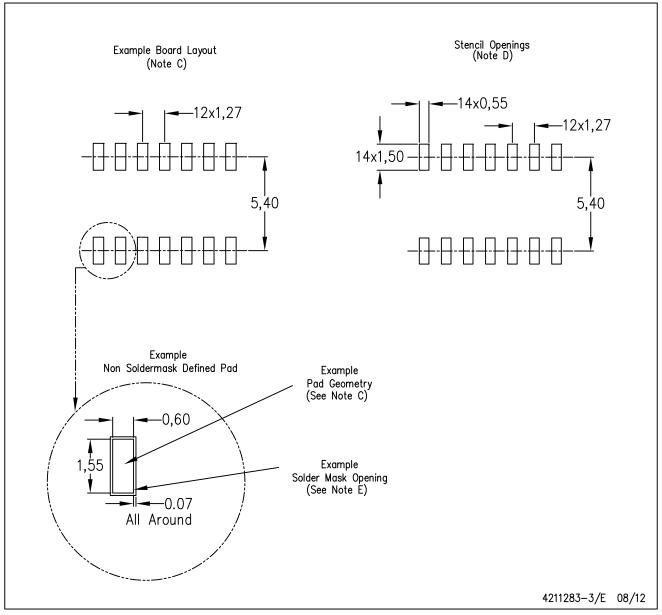


- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AB.



# D (R-PDSO-G14)

### PLASTIC SMALL OUTLINE



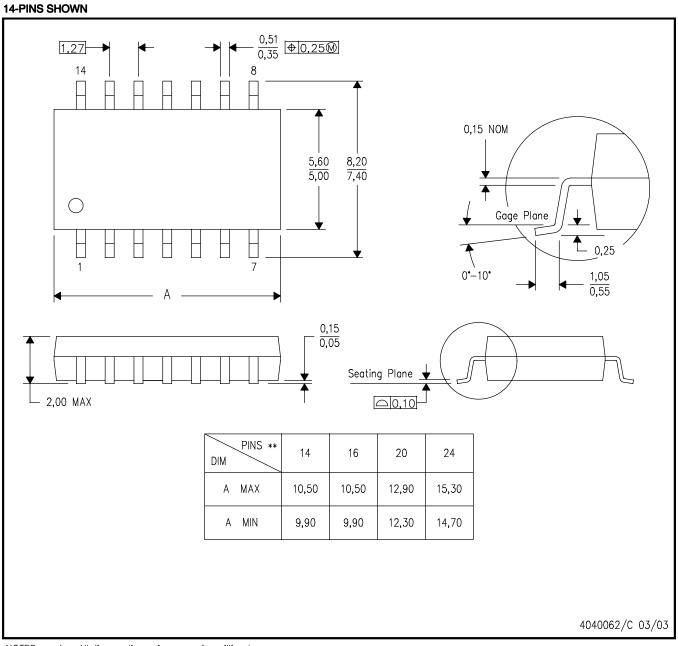
- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



### **MECHANICAL DATA**

### NS (R-PDSO-G\*\*)

### PLASTIC SMALL-OUTLINE PACKAGE



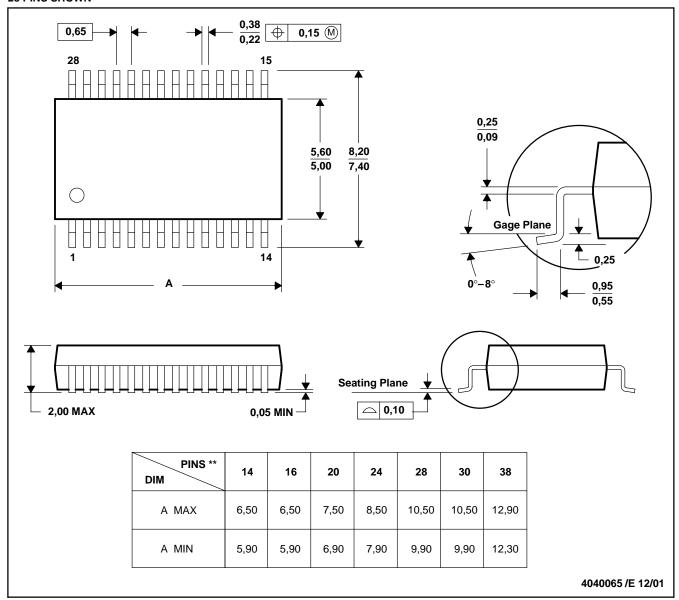
- All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



### DB (R-PDSO-G\*\*)

### PLASTIC SMALL-OUTLINE

### **28 PINS SHOWN**



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.

D. Falls within JEDEC MO-150

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